

15A, 150V - 200V Trench Schottky Surface Mount Rectifier

FEATURES

TAIWAN

- Patented Trench Schottky technology
- Excellent high temperature stability

EMICONDUCTOR

- Low forward voltage
- Low power loss / high efficiency
- High forward surge capability
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-277A (SMPC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.095g (approximately)

| VALUE | UNIT |
|----------------|--|
| 15 | А |
| 150 - 200 | V |
| 250 | А |
| 150 | °C |
| TO-277A (SMPC) | |
| Single die | |
| | 15 150 - 200 250 150 TO-277A (|





TO-277A (SMPC)

| Anode 1 O | K | Cathada |
|-----------|----|---------|
| Anode 2 O | -0 | Cathode |

| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | |
|--|---------------------|-------------|------------|------|
| PARAMETER | SYMBOL | TSP15H150S | TSP15H200S | UNIT |
| Marking code on the device | | 15H150 | 15H200 | |
| Repetitive peak reverse voltage | V _{RRM} | 150 | 200 | V |
| Reverse voltage, total rms value | V _{R(RMS)} | 105 | 140 | V |
| Forward current | I _F | 1 | 5 | А |
| Surge peak forward current, 8.3ms single half sine wave superimposed on rated load | I _{FSM} | 250 | | A |
| Junction temperature | TJ | -55 to +150 | | °C |
| Storage temperature | T _{STG} | -55 to +150 | | °C |



| THERMAL PERFORMANCE | | | |
|-------------------------------------|------------------|-----|------|
| PARAMETER | SYMBOL | ТҮР | UNIT |
| Junction-to-lead thermal resistance | R _{eJL} | 9 | °C/W |

| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | | |
|--|--------------------------|--|----------------|------|------|------|
| PARAMETER | | CONDITIONS | SYMBOL | ТҮР | MAX | UNIT |
| | TSP15H150S | | | 0.69 | - | V |
| | TSP15H200S | I _F = 7.5A, T _J = 25°C | | 0.73 | - | V |
| | TSP15H150S | | | 0.75 | 0.84 | V |
| | TSP15H2008 | I _F = 15.0A, T _J = 25°C | N | 0.79 | 0.89 | V |
| Forward voltage ⁽¹⁾ | TSP15H150S | | V _F | 0.56 | - | V |
| | TSP15H200S | I _F = 7.5A, T _J = 125°C | | 0.59 | - | V |
| | | | | 0.63 | 0.73 | V |
| | TSP15H200S | I _F = 15.0A, T _J = 125°C | | 0.66 | 0.76 | V |
| Reverse current | TSP15H150S TSP15H200S | $I_{\rm J} = 25^{\circ}{\rm C}$ | | - | 150 | μA |
| @ rated V _R ⁽²⁾ | TSP15H150S TSP15H200S | | Ι _R | - | 25 | mA |

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

| ORDERING INFORMATION | | | |
|------------------------------|----------------|---------------------|--|
| ORDERING CODE ⁽¹⁾ | PACKAGE | PACKING | |
| TSP15HxS | TO-277A (SMPC) | 6,000 / Tape & Reel | |

Notes:

1. "x" defines voltage from 150V(TSP15H150S) to 200V(TSP15H200S)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

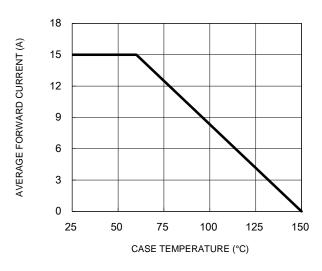


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

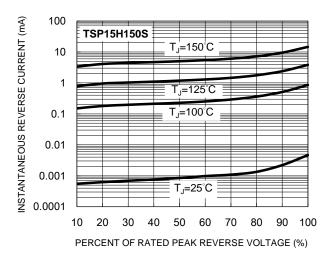
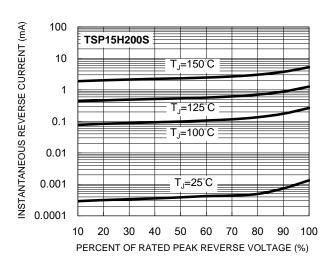


Fig.5 Typical Reverse Characteristics



10000 (g) 1000 1000 1000 1000 (g) 1000 (

Fig.4 Typical Forward Characteristics

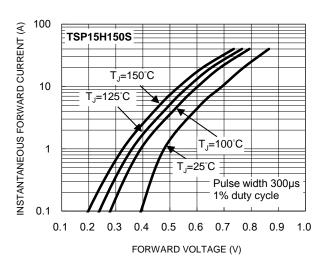


Fig.6 Typical Forward Characteristics

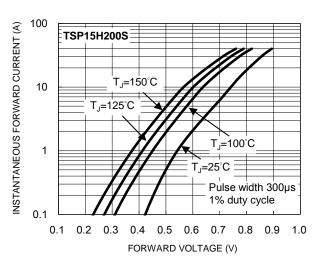
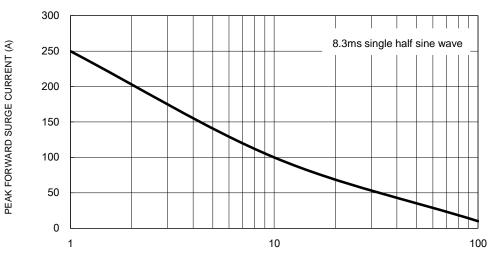


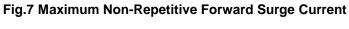
Fig.2 Typical Junction Capacitance



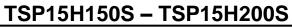
CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



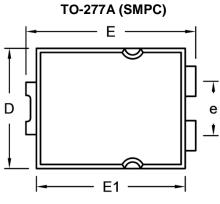


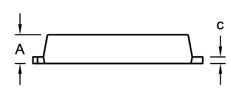
NUMBER OF CYCLES AT 60 Hz

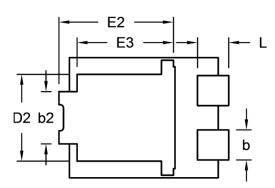


PACKAGE OUTLINE DIMENSIONS

5 TAIWAN SEMICONDUCTOR

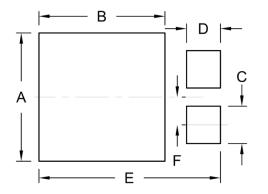




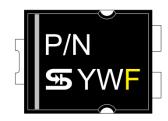


| DIM. | Unit (mm) | | Unit (| (inch) |
|------|-----------|-------|--------|--------|
| | Min. | Max. | Min. | Max. |
| A | 1.000 | 1.200 | 0.039 | 0.047 |
| b | 1.000 | 1.300 | 0.039 | 0.051 |
| b2 | 1.850 | 2.150 | 0.073 | 0.085 |
| с | 0.175 | 0.325 | 0.007 | 0.013 |
| D | 4.550 | 4.650 | 0.179 | 0.183 |
| D2 | 3.170 | 3.470 | 0.125 | 0.137 |
| E | 6.350 | 6.650 | 0.250 | 0.262 |
| E1 | 5.650 | 5.750 | 0.222 | 0.226 |
| E2 | 4.235 | 4.535 | 0.167 | 0.179 |
| E3 | 3.540 | 3.840 | 0.139 | 0.151 |
| е | 1.930 | 2.230 | 0.076 | 0.088 |
| L | 1.043 | 1.343 | 0.041 | 0.053 |

SUGGESTED PAD LAYOUT



MARKING DIAGRAM



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| А | 4.80 | 0.189 |
| В | 4.72 | 0.186 |
| С | 1.40 | 0.055 |
| D | 1.27 | 0.050 |
| E | 6.80 | 0.268 |
| F | 1.04 | 0.041 |

P/N = Marking Code

YW = Date Code

F = Factory Code



TSP15H150S - TSP15H200S

Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.